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April 2001

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Si3457DV

Single P-Channel Logic Level PowerTrench[®] MOSFET

General Description

FAIRCHILD

This P-Channel Logic Level MOSFET is produced using Fairchild's advanced PowerTrench process. It has been optimized for battery power management applications.

Applications

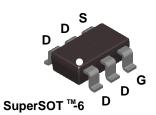
- Battery management
- · Load switch
- Battery protection

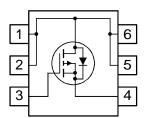
Features

• -4 A, -30 V.
$$R_{DS(ON)} = 50 \text{ m}\Omega @ V_{GS} = -10 \text{ V}$$

 $R_{DS(ON)} = 75 \text{ m}\Omega @ V_{GS} = -4.5 \text{ V}$

- · Low gate charge
- High performance trench technology for extremely low R_{DS(ON)}





Absolute Maximum Ratings T_{A=25°C unless otherwise noted}

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-Source Voltage		-30	V	
V _{GSS}	Gate-Source Voltage		±25	V	
ID	Drain Current – Continuous	(Note 1a)	-4	A	
	– Pulsed		-20		
P _D	Maximum Power Dissipation	(Note 1a)	1.6	W	
		(Note 1b)	0.8		
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C	

$R_{ ext{ hetaJA}}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	78	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	30	°C/W

Package Marking and Ordering Information

Device Reel Size Tape width Quantity	Device	Device Marking
Si3457DV 7" 8mm 3000 units	Si3457DV	.457
515457 <i>D</i> 7 01111	01040707	.457

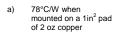
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Si3457DV

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V, I_D = -250 \mu A$	-30			V
<u>ΔBVdss</u> ΔTJ	Breakdown Voltage Temperature Coefficient	$I_D = -250 \mu$ A,Referenced to 25°C		-22		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -24 V$, $V_{GS} = 0 V$			-1	μA
I _{GSSF}	Gate-Body Leakage, Forward	$V_{GS} = 25 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			100	nA
IGSSR	Gate-Body Leakage, Reverse	$V_{GS} = -25 \text{ V} \qquad V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-1	-1.8	-3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}, \text{Referenced to } 25^{\circ}\text{C}$		4		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{ccc} V_{GS} = -10 \ V, & I_D = -4 \ A \\ V_{GS} = -4.5 \ V, & I_D = -3.4 \ A \\ V_{GS} = -10 \ V, \ I_D = -4 \ A; T_J = 125^{\circ} \end{array} $		44 67 60	50 75 70	mΩ
I _{D(on)}	On–State Drain Current	$V_{GS} = -10 \text{ V}, \qquad V_{DS} = -5 \text{ V}$	-20			Α
g fs	Forward Transconductance	$V_{\text{DS}} = -5 \text{ V}, \qquad I_{\text{D}} = -4 \text{ A}$		8.4		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = -15 V$, $V_{GS} = 0 V$,		470		pF
Coss	Output Capacitance	f = 1.0 MHz		126		pF
C _{rss}	Reverse Transfer Capacitance	7		61		pF
Switchir	g Characteristics (Note 2)	·		•	•	
t _{d(on)}	Turn–On Delay Time	$V_{DD} = -15 V$, $I_D = -1 A$,		7	14	ns
t _r	Turn–On Rise Time	$V_{GS} = -10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		12	22	ns
t _{d(off)}	Turn–Off Delay Time	7		16	29	ns
t _f	Turn–Off Fall Time			6	12	ns
Q _g	Total Gate Charge	$V_{DS} = -15 V$, $I_{D} = -4 A$,		6	8.1	nC
Q _{gs}	Gate-Source Charge	$V_{GS} =5 V$		2.1		nC
Q _{gd}	Gate-Drain Charge	7		2		nC
Drain-S	ource Diode Characteristics	and Maximum Ratings				
l _s	Maximum Continuous Drain–Source				-1.3	Α
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_{S} = -1.3 A$ (Note 2)		-0.77	-1.2	V

 $R_{\theta JA}$ is the sum of the junction-to-case and case-to-amplent merinal resistance where the case dominant of the sum of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.





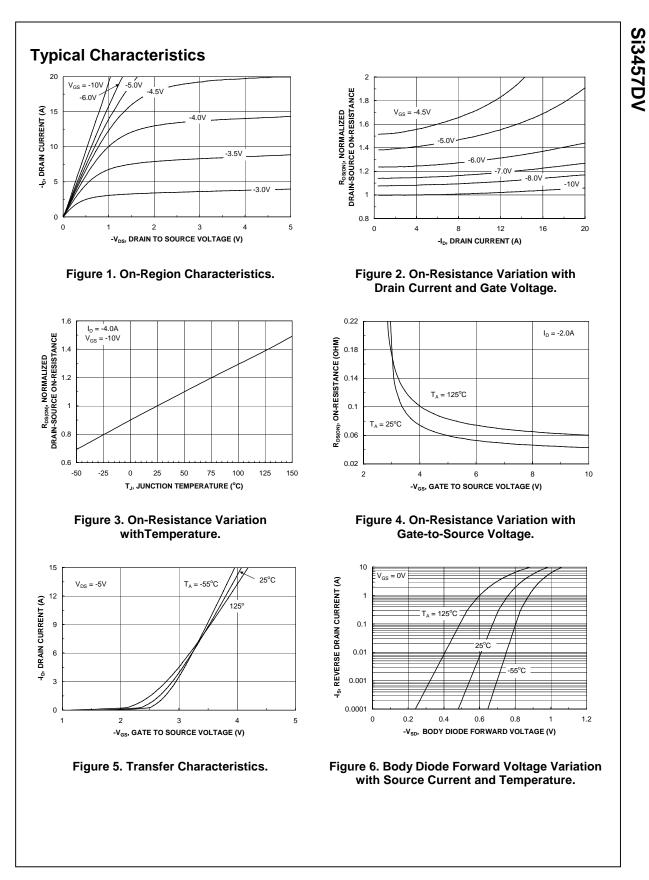


b) 156°C/W when mounted on a minimum pad of 2 oz copper

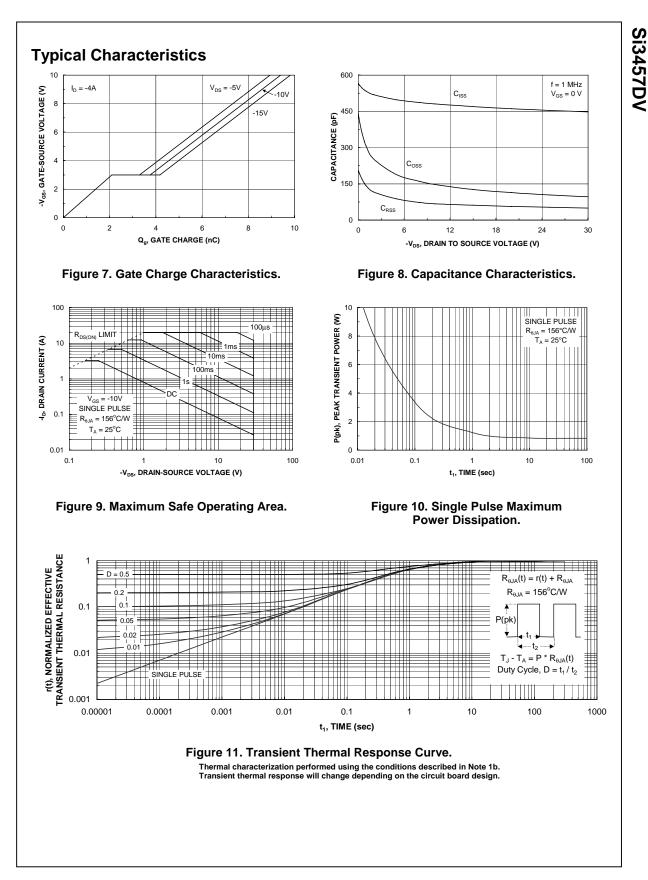
Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty Cycle < 2.0%

Si3457DV Rev A1 (W)



Si3457DV Rev A1 (W)



Si3457DV Rev A1 (W)

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Definition of Terms

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		Rev. I11

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